

## Surface Mount Switching Diodes

**(Pb)** Lead(Pb)-Free

### Features:

- \* Fast Switching Speed
- \* Surface Mount Package Ideally Suited for Automatic Insertion
- \* High Conductance
- \* For General Purpose Switching Applications

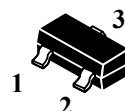
### Mechanical Data:

- \* Case: SOT-23, Molded Plastic
- \* Terminals: Solderable per MIL-STD-202, Method 208
- \* Polarity: See diagram
- \* Weight: 0.008 grams

**SWITCHING DIODE**

**100m AMPERES**

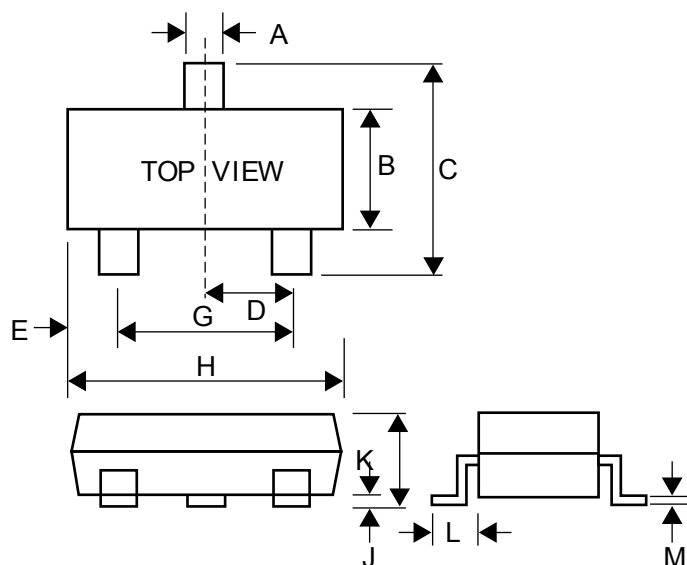
**80 VOLTS**



**SOT-23**

## SOT-23 Outline Dimensions

Unit:mm



Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25

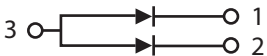
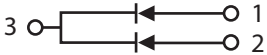




## Maximum Ratings (T<sub>J</sub>=125°C Unless otherwise noted)

Characteristic	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	80	V
Forward Current	I <sub>F</sub>	100	mA
Power Dissipation	P <sub>D</sub>	150	mW
Operating Junction Temperature Range	T <sub>J</sub>	-55 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

## Electrical Characteristics (T<sub>J</sub>=125°C Unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Reverse Breakdown Voltage I <sub>R</sub> =100μA	V <sub>(BR)</sub>	80	-	V
Forward Voltage I <sub>F</sub> =100mA	V <sub>F</sub>	-	1.2	V
Reverse Leakage V <sub>R</sub> =80V	I <sub>R</sub>	-	0.5	μA
Total Capacitance V <sub>R</sub> =0V, f=1.0MHz	C <sub>D</sub>	-	4.0	pF
Reverse Recover Time	T <sub>rr</sub>	-	4	nS

## Device Marking

Item	Marking	Equivalent Circuit diagram
1SS181	A3	
1SS184	B3	
1SS187	D3	
1SS190	E3	
1SS193	F3	
1SS196	G3	
1SS226	C3	